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<u>TOSHIBA</u>

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC299F,TC74VHC299FW,TC74VHC299FT

8-Bit Pipo Shift Register with Asynchronous Clear

The TC74VHC299 is an advanced high speed CMOS 8-BIT PIPO SHIFT REGISTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

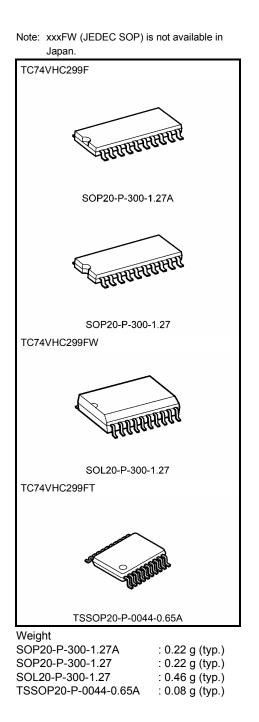
It has a four modes (HOLD, SHIFT LEFT, SHIFT RIGHT and LOAD DATA) controlled by the two selection inputs (S0, S1).

When one or both enable $(\overline{G}1, \overline{G}2)$ are high, the eight I/O are forced to the high-impedance state; however, sequential operation or clearing of the register is not affected.

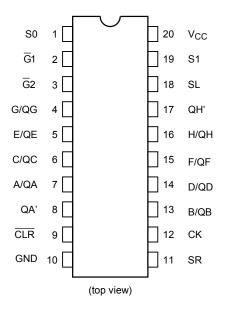
All inputs are equipped with protection circuits against static discharge.

Features (Note 1) (Note 2) (Note 3)

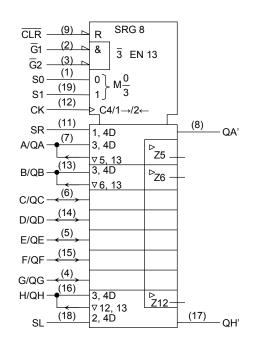
- High speed: $f_{max} = 160 \text{ MHz}$ (typ.) at VCC = 5 V
- Low power dissipation: $I_{CC} = 4 \mu A \pmod{at Ta} = 25 \circ C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 5.5 V
- Low noise: VOLP = 1.4 V (max)
- Pin and function compatible with 74ALS299
 - Note 1: Do not apply a signal to A/QA to H/QH bus terminal when it is in the output mode. Damage may result.
 - Note 2: All floating (high impedance) A/QA to H/QH bus terminals must have their input levels fixed by means of pull up or pull down resistors.
 - Note 3: A parasitic diode is formed between A/QA to H/QH bus and V_{CC} terminals. Therefore bus terminal can not be used to interface 5 V to 3 V systems directly.



Pin Assignment



IEC Logic Symbol



Truth Table

| | | Inputs | | | | | | | | Inputs /Outputs | | puts |
|-------------|--------------------|--------|----------------|--------------|--------------|--------|----|------|-----------------|--------------------|-----------------|-----------------|
| Mode | Function Select | | Output Control | | ск | Serial | | A/QA | | | | |
| | CLR | S1 | S0 | G1 (Note) | G2 (Note) | - | SL | SR | AVQA | H/QH | QA' | QH' |
| Z | L | Н | Н | Х | Х | Х | Х | Х | Z | Z | L | L |
| Clear | L | L | Х | L | L | Х | Х | Х | L | L | L | L |
| Clear | L | х | L | L | L | х | х | х | L | L | L | L |
| Hold | Н | L | L | L | L | Х | Х | Х | QA ₀ | QH ₀ | QA ₀ | QH ₀ |
| Shift Right | Н | L | Н | L | L | | Х | Н | Н | QGn | Н | QGn |
| | н | L | н | L | L | | х | L | L | QGn | L | QGn |
| Shift Left | Н | Н | L | L | L | | Н | Х | QBn | Н | QBn | Н |
| Shift Left | Н | Н | L | L | L | | L | х | QBn | L | QBn | L |
| Load | Н | Н | Н | Х | Х | | Х | Х | а | h | а | h |

Note: When one or both output controls are high, the eight input/output terminals are in the high-impedance state; however sequential or clearing of the register is not affected.

Z: High impedance

 $\mathsf{Q}_{n0}\!:$ The level of Q_n before the indicated steady-state input conditions were established.

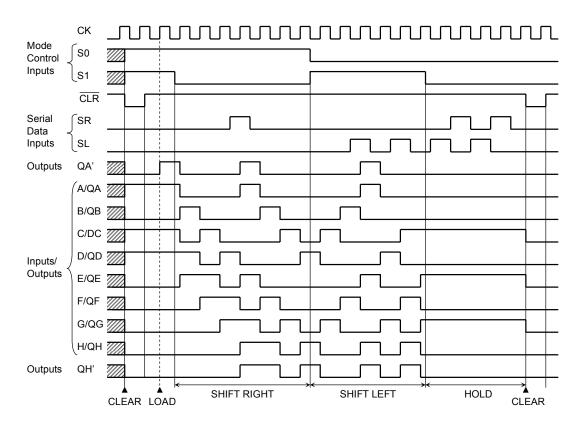
 $Q_{nn}:$ The level of Q_n before the most recent active transition indicated by \downarrow or $\uparrow.$

a, h: The level of the steady-state inputs A, H, respectively.

X: Don't care.

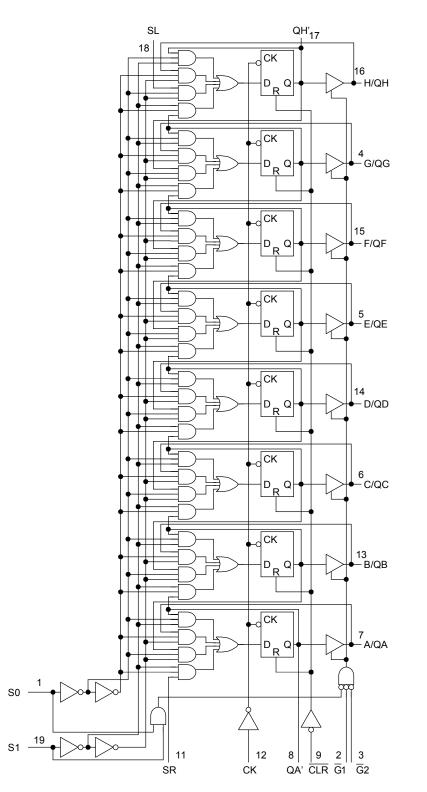
<u>TOSHIBA</u>

Timing Chart



TOSHIBA

System Diagram



Absolute Maximum Ratings (Note)

| Characteristics | Symbol | Rating | Unit |
|---------------------------------------|---------------------|-------------------------------|------|
| Supply voltage range | V _{CC} | -0.5 to 7.0 | V |
| DC input voltage | V _{IN} | -0.5 to 7.0 | V |
| DC bus I/O voltage (A/QA to H/QH') | V _{IN/OUT} | -0.5 to V _{CC} + 0.5 | V |
| DC output voltage (QA' to QH') | V _{OUT} | -0.5 to V _{CC} + 0.5 | v |
| Input diode current | IIK | -20 | mA |
| Output diode current | IOK | ±20 | mA |
| DC output current | IOUT | ±25 | mA |
| DC V _{CC} /ground current | ICC | ±80 | mA |
| Power dissipation | PD | 180 | mW |
| Storage temperature | T _{stg} | -65 to 150 | °C |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

| Characteristics | Symbol | Rating | Unit | |
|--------------------------|---------------------|---|--------------|--|
| Supply voltage | V _{CC} | 2.0 to 5.5 | V | |
| Input voltage | V _{IN} | 0 to 5.5 | V | |
| DC bus I/O voltage | Manager | 0 to 1/ | V | |
| (A/QA to H/QH) | V _{IN/OUT} | 0 to V _{CC} | v | |
| DC output voltage | | | V | |
| (QA' to QH') | Vout | 0 to V _{CC} | v | |
| Operating temperature | T _{opr} | -40 to 85 | °C | |
| land tring and fall time | alt (al) (| 0 to 100 (V _{CC} = 3.3 ± 0.3 V) | 7 00/ | |
| Input rise and fall time | dt/dV | 0 to 20 (V _{CC} = 5 \pm 0.5 V) | ns/V | |

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

| Characteristics | Symbol | Test Condition | | | ٢ | ⊺a = 25°(| 0 | | a = 0 85°C | Unit |
|-------------------------------------|-----------------|--|--------------------------|---------------|--------------------------|-----------|--------------------------|--------------------------|--------------------------|------|
| | | | | $V_{CC}(V)$ | Min | Тур. | Max | Min | Max | |
| High-level input | | _ | | 2.0 | 1.50 | _ | _ | 1.50 | _ | |
| voltage | VIH | | | 3.0 to 5.5 | V _{CC} × 0.7 | _ | _ | V _{CC} × 0.7 | _ | V |
| Low-level input | | | | 2.0 | _ | _ | 0.50 | _ | 0.50 | |
| voltage | VIL | | _ | 3.0 to 5.5 | _ | _ | V _{CC} × 0.3 | _ | V _{CC} × 0.3 | V |
| | | | | 2.0 | 1.9 | 2.0 | _ | 1.9 | _ | |
| | V _{OH} | | I _{OH} = -50 μA | 3.0 | 2.9 | 3.0 | — | 2.9 | _ | |
| High-level output voltage | | V _{IN} = V _{IH} or V _{IL} | | 4.5 | 4.4 | 4.5 | — | 4.4 | _ | V |
| | | | I _{OH} = −4 mA | 3.0 | 2.58 | _ | _ | 2.48 | _ | |
| | | | I _{OH} = −8 mA | 4.5 | 3.94 | _ | — | 3.80 | _ | |
| | V _{OL} | V _{IN} = V _{IH} or V _{IL} | | 2.0 | _ | 0.0 | 0.1 | _ | 0.1 | |
| | | | I _{OL} = 50 μA | 3.0 | — | 0.0 | 0.1 | — | 0.1 | |
| Low-level output voltage | | | | 4.5 | — | 0.0 | 0.1 | — | 0.1 | V |
| 0 | | | I _{OL} = 4 mA | 3.0 | _ | _ | 0.36 | _ | 0.44 | |
| | | | I _{OL} = 8 mA | 4.5 | — | — | 0.36 | — | 0.44 | |
| 3-state output off-state current | I _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$ | | 5.5 | _ | _ | ±0.25 | _ | ±2.50 | μA |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | _ | ±0.1 | _ | ±1.0 | μA |
| Quiescent supply current | ICC | V _{IN} = V _{CC} or | GND | 5.5 | _ | | 4.0 | _ | 40.0 | μA |

AC Characteristics (input: t_r = t_f = 3 ns)

| Characteristics | Symbol | Τe | Test Condition | | - | Ta = 25°(| Ta = 25°C Ta = -40 to 85°C | | | Unit |
|--|--|-----------------------|-------------------------------|---------------------|-----|-----------|----------------------------|----------|------|-------|
| | -) | | V _{CC} (V) | C _L (pF) | Min | Тур. | Max | Min | Max | |
| | | | 22.02 | 15 | _ | 12.2 | 17.2 | 1.0 | 19.8 | |
| Propagation delay time | t _{pLH} | | 3.3 ± 0.3 | 50 | | 14.7 | 20.7 | 1.0 | 23.3 | |
| (CK-QA', QH') | t _{pHL} | _ | 50.05 | 15 | | 8.5 | 10.8 | 1.0 | 12.0 | ns |
| | | | 5.0 ± 0.5 | 50 | | 10.0 | 12.8 | 1.0 | 14.0 | |
| | | | 22.02 | 15 | | 13.0 | 19.0 | 1.0 | 22.0 | |
| Propagation delay time | | | 3.3 ± 0.3 | 50 | | 15.5 | 22.5 | 1.0 | 25.5 | |
| (CLR -QA', QH') | t _{pHL} | _ | 50.05 | 15 | | 9.1 | 11.2 | 1.0 | 13.5 | ns |
| (| | | 5.0 ± 0.5 | 50 | | 10.8 | 13.2 | 1.0 | 15.5 | |
| | | | | 15 | | 10.3 | 14.3 | 1.0 | 16.6 | |
| Propagation delay time | ^t pLH t _{pHL} | | 3.3 ± 0.3 | 50 | | 12.8 | 17.8 | 1.0 | 20.1 | |
| (CK-QA to QH) | | _ | 50.05 | 15 | _ | 7.3 | 9.1 | 1.0 | 10.4 | ns |
| (| | | 5.0 ± 0.5 | 50 | | 8.8 | 11.1 | 1.0 | 12.4 | |
| Propagation delay time t _p - | | | | 15 | | 10.8 | 17.0 | 1.0 19.5 | 19.5 | |
| | | | 3.3 ± 0.3 | 50 | | 13.3 | 20.5 | 1.0 | 23.0 | |
| | tpHL | | 5.0 ± 0.5 | 15 | | 7.7 | 10.5 | 1.0 | 12.0 | ns |
| () | | | | 50 | | 9.2 | 12.5 | 1.0 | 14.0 | |
| | t _P ZL t _P ZH | R _L = 1 kΩ | 3.3 ± 0.3 | 15 | | 13.3 | 16.5 | 1.0 | 19.2 | ns |
| Output anabla time | | | | 50 | | 14.8 | 19.0 | 1.0 | 21.7 | |
| Output enable time | | | 5.0 ± 0.5 | 15 | | 8.9 | 9.7 | 1.0 | 11.3 | |
| | | | | 50 | | 10.4 | 11.2 | 1.0 | 12.6 | |
| Output dischle time | t _{pLZ} | D 110 | $\textbf{3.3}\pm\textbf{0.3}$ | 50 | | 18.0 | 21.3 | 1.0 | 24.3 | |
| Output disable time | t _{pHZ} | $R_L = 1 \ k\Omega$ | 5.0 ± 0.5 | 50 | | 11.8 | 13.2 | 1.0 | 15.0 | ns |
| | | | 22102 | 15 | 65 | 100 | _ | 55 | _ | |
| Maximum clock | £ | | 3.3 ± 0.3 | 50 | 55 | 90 | | 50 | _ | N411- |
| frequency | f _{max} | _ | 5.0 ± 0.5 | 15 | 125 | 160 | _ | 110 | - | MHz |
| | | | 5.0 ± 0.5 | 50 | 115 | 150 | | 100 | _ | |
| Input capacitance | C _{IN} | | · _ | | _ | 4 | 10 | _ | - | pF |
| Bus I/O capacitance | Course | | | | | 0 | | | | n E |
| (A/QA to H/QH) | C _{OUT} | | _ | | _ | 8 | _ | | | pF |
| Power dissipation capacitance | C _{PD} | | | (Note) | _ | 110 | _ | — | _ | pF |

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

| Characteristics | Symbol | Test Condition | Test Condition | | Ta = 25°C | | Unit |
|----------------------|--------------------|----------------|----------------|------|-----------|-------|------|
| | | | $V_{CC}(V)$ | Тур. | Limit | Limit | |
| Minimum pulse width | t _{w (H)} | | 3.3 ± 0.3 | _ | 7.0 | 8.0 | ns |
| (CK) | t _{w (L)} | — | 5.0 ± 0.5 | — | 7.0 | 8.0 | 115 |
| Minimum pulse width | 4 | | 3.3 ± 0.3 | _ | 6.0 | 7.0 | ns |
| (CLR) | t _{w (L)} | — | 5.0 ± 0.5 | — | 6.0 | 7.0 | ns |
| Minimum set-up time | + | | 3.3 ± 0.3 | _ | 8.5 | 10.0 | 20 |
| (SL, SR) | t _s | — | 5.0 ± 0.5 | — | 5.0 | 5.0 | ns |
| Minimum set-up time | | | 3.3 ± 0.3 | _ | 8.0 | 9.0 | |
| (A to H) | t _s | — | 5.0 ± 0.5 | — | 4.0 | 4.0 | ns |
| Minimum set-up time | | | 3.3 ± 0.3 | | 14.5 | 17.0 | |
| (S0, S1) | t _s | — | 5.0 ± 0.5 | — | 7.0 | 8.0 | ns |
| Minimum hold time | | | 3.3 ± 0.3 | _ | 1.0 | 1.0 | |
| (SL, SR) | t _h | — | 5.0 ± 0.5 | — | 1.0 | 1.0 | ns |
| Minimum hold time | | | 3.3 ± 0.3 | _ | 0.5 | 0.5 | |
| (A to H) | t _h | — | 5.0 ± 0.5 | — | 1.5 | 1.5 | ns |
| Minimum hold time | • | | 3.3 ± 0.3 | _ | 0 | 0 | 20 |
| (S0, S1) | t _h | _ | 5.0 ± 0.5 | — | 0.5 | 0.5 | ns |
| Minimum removal time | + | | 3.3 ± 0.3 | _ | 5.0 | 6.0 | 20 |
| (CLR) | t _{rem} | _ | 5.0 ± 0.5 | — | 4.0 | 4.0 | ns |

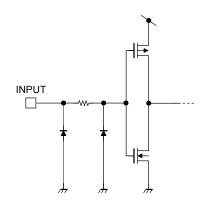
Noise Characteristics (input: t_r = t_f = 3 ns) (Note)

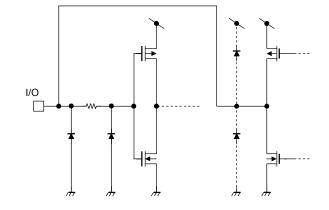
| Characteristics | Symbol | Test Condition | | Ta = | 25°C | Unit |
|--|------------------|------------------------|-------------|--------|--------|------|
| Characteristics | Symbol | | $V_{CC}(V)$ | Тур. | Limit | |
| Quiet output maximum dynamic | V _{OLP} | C _I = 50 pF | 5.0 | 0.9 | 1.2 | v |
| V _{OL} | VOLP | CL - 50 pr | 5.0 | (1.0) | (1.4) | v |
| Quiet output minimum dynamic | V _{OLV} | C _I = 50 pF | 5.0 | -0.9 | -1.2 | v |
| V _{OL} | VOLV | CL - 50 pr | 5.0 | (-1.0) | (-1.4) | v |
| Minimum high level dynamic input Voltage | V _{IHD} | C _L = 50 pF | 5.0 | Ι | 3.5 | V |
| Maximum low high level dynamic input Voltage | V _{ILD} | C _L = 50 pF | 5.0 | _ | 1.5 | V |

Note: The value in () only applies to JEDEC SOP (FW) devices.

Input Equivalent Circuit

A/QA to H/QH Bus Terminal Equivalent Circuit

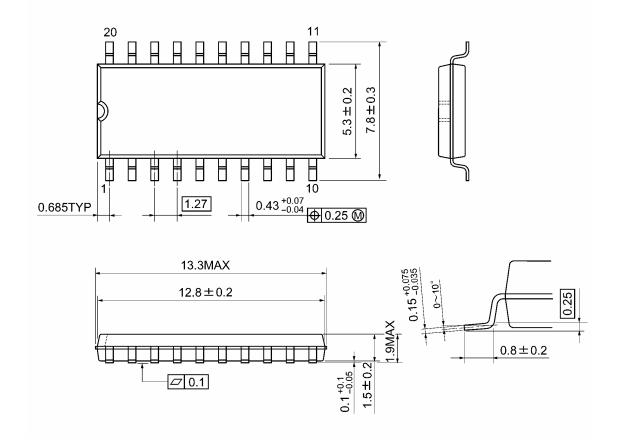




Package Dimensions

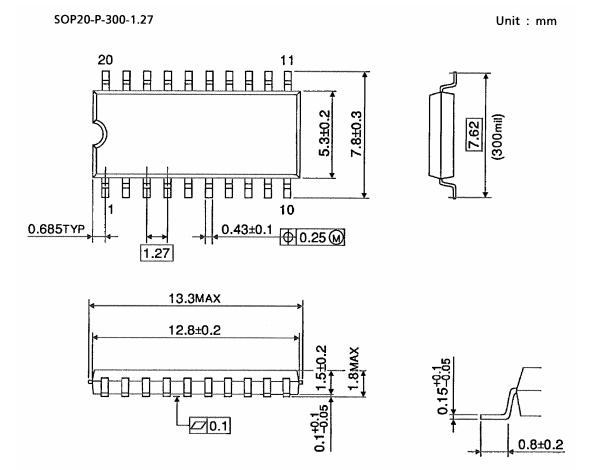
SOP20-P-300-1.27A

Unit: mm



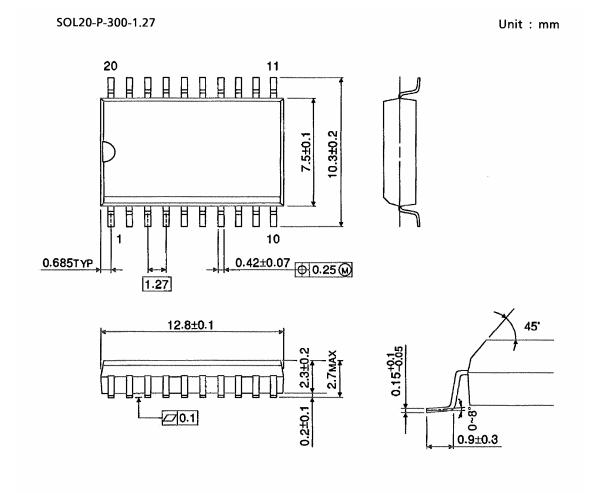
Weight: 0.22 g (typ.)

Package Dimensions



Weight: 0.22 g (typ.)

Package Dimensions (Note)



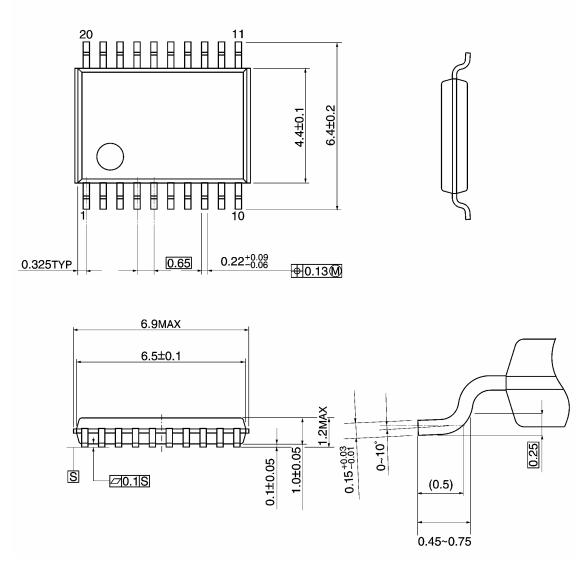
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



Weight: 0.08 g (typ.)

Note: Lead (Pb)-Free Packages SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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060116EBA

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